

INCHANGE SEMICONDUCTOR

Isc N-Channel MOSFET Transistor

SPA04N60C3

- FEATURES
- With TO-220F Package
- Drain Source Voltage-
- : V_{DSS}=600V(Min)
- Static Drain-Source On-Resistance : R_{DS(on)} = 0.95 Ω (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

Switching applications

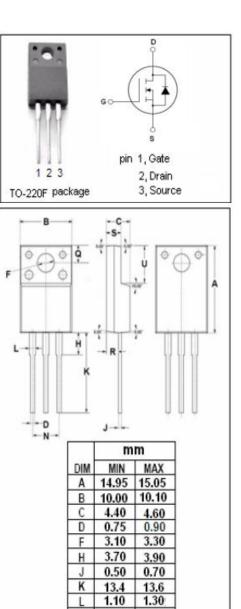
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	600	V
V _{GSS}	Gate-Source Voltage	±20	V
ID	Drain Current-Continuous @Tc=25℃ (V _{GS} at 10V) Tc=100℃	4.5 2.8	A
I _{DM}	Drain Current-Single Pulsed	13.5	A
PD	Total Dissipation @T _C =25°C	31	W
Tj	Max. Operating Junction Temperature	-55~150	°C
T _{stg}	Storage Temperature	-55~150	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	4	°C/W
Rth(ch-a)	Channel-to-ambient thermal resistance	80	°C/W

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 N
 5.00
 5.20

 Q
 2.70
 2.90

 R
 2.20
 2.40

 S
 2.65
 2.90

 U
 6.40
 6.60

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• ELECTRICAL CHARACTERISTICS

 $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =0.25mA	600			V
V _{GS(th)}	Gate Threshold Voltage	V_{DS} = V_{GS} ; I _D =200uA	2.1	3	3.9	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =2.8A		0.85	0.95	Ω
I _{GSS}	Gate-Source Leakage Current	V_{GS} = ±30V; V_{DS} = 0V			±100	nA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 600V; V _{GS} = 0V;Tj=25℃ V _{DS} = 600V; V _{GS} = 0V; Tj=150℃		0.5	1 50	μA
V _{SDF}	Diode forward voltage	I _{SD} =4.5A, V _{GS} = 0 V		1	1.2	V

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